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DATA SHEET

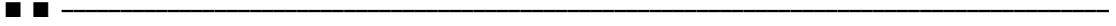
O K I A S I C P R O D U C T S

MG113P/114P/115P/73P/74P/75P 0.25μm Sea of Gates and Customer Structured Arrays

November 1999



Oki Semiconductor



Oki Semiconductor

MG113P/114P/115P/73P/74P/75P

0.25µm Sea of Gates and Customer Structured Arrays

DESCRIPTION

Oki's 0.25µm Application-Specific Integrated Circuit (ASIC) products are available in both Sea Of Gates (SOG) and Customer Structured Array (CSA) architectures. Both the SOG-based MG115P series and the CSA-based MG75P series use a five-layer metal process on 0.25µm drawn (0.18µm L-effective) CMOS technology. The SOG MG113P/114P series uses the same SOG base-array architecture as the MG115P series, but offers four and three metal layers, respectively. The MG73P/74P CSA series uses three and four metal layers, respectively. The semiconductor process is adapted from Oki's production-proven 64-Mbit DRAM manufacturing process.

The 0.25µm family provides significant performance, density, and power improvement over previous 0.30 and 0.35µm technologies. An innovative 4-transistor cell structure, licensed from In-Chip Systems, Inc., provides 30 to 50% less power and 30 to 50% more usable gates than traditional cell designs. The Oki 0.25µm family operates using 2.5-V V_{DD} core with optimized 3-V I/O buffers. The 3-, 4-, and 5-layer metal MG113P/114P/115P SOG series contains 4 array bases, offering up to 588 I/O pads and over 2.4M raw gates. The 3-, 4-, and 5-layer metal MG73P/74P/75P CSA series contains 21 array bases, offering up to 868 I/O pads and over 5.4M raw gates. These SOG and CSA array sizes are designed to fit the most popular quad flat pack (QFP), low profile QFPs (LQFPs), thin QFPs (TQFPs), and plastic ball grid array (PBGA) packages.

The MG113P/114P/115P series SOG architecture allows rapid prototyping turnaround times (TATs), additionally offering the most cost-effective solution for pad-limited circuits (particularly the 3-layer metal MG113P series). The 3-layer-metal MG73P, 4-layer-metal MG74P and 5-layer-metal MG75P CSA series contains 21 array bases, offering a wider span of gate and I/O counts than the SOG series. Oki uses the Artisan Components memory compiler which provides high performance, embedded synchronous single- and dual-port RAM macrocells for CSA designs. As such, the MG73P/74P/75P series is suited to memory-intensive ASICs and high-volume designs where fine tuning of package size produces significant cost or real-estate savings.

FEATURES

- 0.25 μ m drawn 3-, 4-, and 5-layer metal CMOS
- Optimized 2.5-V core
- Optimized 3-V I/O
- SOG and CSA architecture availability
- 77-ps typical gate propagation delay (for a 4x-drive inverter gate with a fanout of 2 and 0 mm of wire, operating at 2.5 V)
- Over 5.4M raw gates and 868 I/O pads using 60 μ staggered I/O
- User-configurable I/O with V_{SS}, V_{DD}, TTL, 3-state, and 1- to 24-mA options
- Slew-rate-controlled outputs for low-radiated noise
- H-clock tree cells which reduces the maximum skew for clock signals
- Low 0.2 μ W/MHz/gate power dissipation
- User-configurable single- and dual-port memories
- Specialized IP cores and macrocells including 32-bit ARM7TDMI CPU, phase-locked loop (PLL), and peripheral component interconnect (PCI) cells
- Floorplanning for front-end simulation, back-end layout controls, and link to synthesis
- Joint Test Action Group (JTAG) boundary scan and scan path Automatic Test Pattern Generation (ATPG)
- Support for popular CAE systems including Cadence, IKOS, Mentor Graphics, Model Technology, Inc. (MTI), Synopsys, and Viewlogic

MG113P/114P/115P/73P/74P/75P FAMILY LISTING

60 μ m Staggered PAD products						MG113P/73P Family 3LM Usable Gates	MG114P/74P Family 4LM Usable Gates	MG115P/75P Family 5LM Usable Gates
SOG Base Array	EA Base Array	No. of Pads	No. of Rows	No. of Columns	No. of Raw Gates			
	MG7xPB02	68	84	280	23,520		22,344	22,344
	MG7xPB04	108	144	480	69,120		65,664	65,664
	MG7xPB06	148	204	680	138,720		131,784	131,784
	MG7xPB08	188	264	880	232,320		218,381	220,704
	MG7xPB10	228	324	1,080	349,920		311,429	332,424
	MG7xPB12	268	384	1,280	491,520		412,877	466,944
MG11xP14	MG7xPB14	308	444	1,480	657,120	387,701	519,125	611,122
	MG7xPB16	348	504	1,680	846,720		635,040	745,114
MG11xP18	MG7xPB18	388	564	1,880	1,060,320	572,573	763,430	901,272
	MG7xPB20	428	624	2,080	1,297,920		882,586	1,025,357
MG11xP22	MG7xPB22	468	684	2,280	1,559,920	732,974	982,498	1,154,045
	MG7xPB24	508	744	2,480	1,845,120		1,107,072	1,310,035
	MG7xPB26	548	804	2,680	2,154,720		1,249,738	1,465,210
MG11xP28	MG7xPB28	588	864	2,880	2,488,320	1,094,861	1,393,459	1,642,291
	MG7xPB30	628	924	3,080	2,845,920		1,536,797	1,821,389
	MG7xPB32	668	984	3,280	3,227,520		1,678,310	2,001,062
	MG7xPB34	708	1,044	3,480	3,633,120		1,816,560	2,179,872
	MG7xPB36	748	1,104	3,680	4,062,720		1,950,106	2,356,378
	MG7xPB38	788	1,164	3,880	4,516,320		2,077,507	2,529,139
	MG7xPB40	828	1,224	4,080	4,993,920		2,197,325	2,696,717
	MG7xPB42	868	1,284	4,280	5,495,520		2,308,118	2,857,670

ARRAY ARCHITECTURE

The primary components of a 0.25 μ m MG113P/114P/115P circuit include:

- I/O base cells
- 60 μ m pad pitch
- Configurable I/O pads for V_{DD}, V_{SS}, or I/O (optimized 3-V I/O)
- V_{DD} and V_{SS} pads dedicated to wafer probing
- Separate power bus for output buffers
- Separate power bus for internal core logic and input buffers
- Core base cells containing N-channel and P-channel pairs, arranged in column of gates
- Isolated gate structure for reduced input capacitance and increased routing flexibility
- Innovative 4-transistor core cell architecture, licensed from In-Chip Systems, Inc

Each array has 24 dedicated corner pads for power and ground use during wafer probing, with four pads per corner. The arrays also have separate power rings for the internal core functions (V_{DDC} and V_{SSC}) and output drive transistors (V_{DDO} and V_{SSO}).

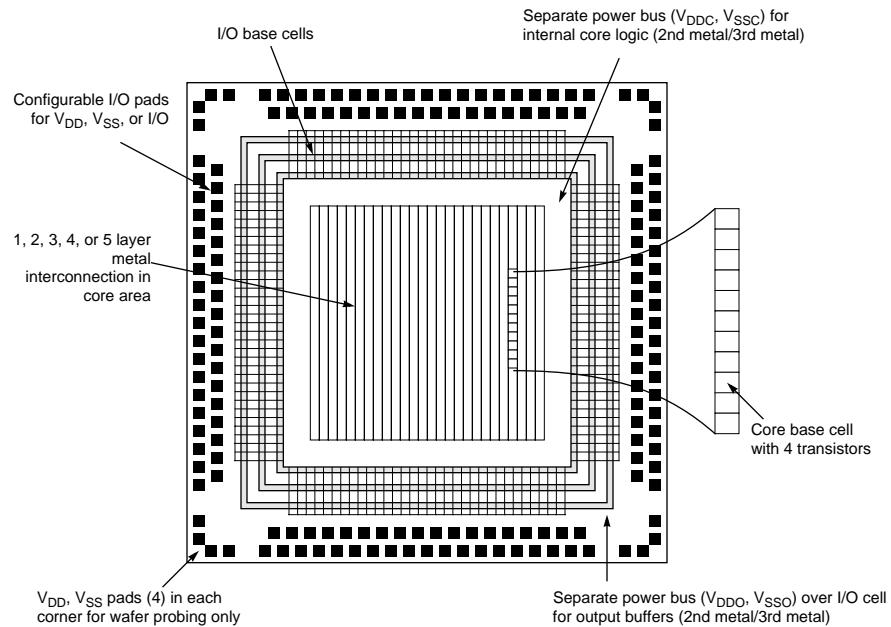


Figure 7. MG115P Array Architecture

MG73P/74P/75P CSA Layout Methodology

The procedure to design, place, and route a CSA follows.

1. Select suitable base array frame from the available predefined sizes. To select an array size:
 - Identify macrocell functions required and minimum array size to hold macrocell functions.
 - Add together all the area occupied by the required random logic and macrocells and select the optimum array.
2. Make a floor plan for the design's megacells.
 - Oki Design Center engineers verify the master slice and review simulation.
 - Oki Design Center or customer engineers floorplan the array using Oki's supported floor-planner or Cadence DP3 or Gambit GFP and customer performance specifications.
 - Using Oki CAD software, Design Center engineers remove the SOG transistors and replace them with diffused memory macrocells to the customer's specifications.

Figure 8 shows an array base after placement of the optimized memory macrocells.

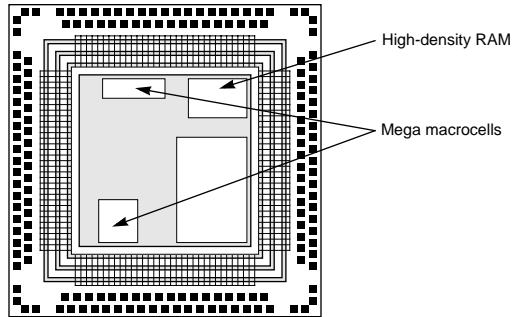


Figure 8. Optimized Memory Macrocell Floor Plan

3. Place and route logic into the array transistors.
 - Oki Design Center engineers use layout software and customer performance specifications to connect the random logic and optimized memory macrocells.

Figure 9 marks the area in which placement and routing is performed with cross hatching.

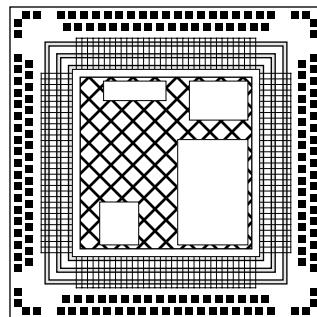


Figure 9. Random Logic Place and Route

ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings ($V_{SS} = 0$ V, $T_J = 25^\circ\text{C}$) ^[1]

Parameter	Symbol	Rated Value	Unit
Power supply voltage	V_{DD} Core (2.5 V)	-0.3 to +3.6	V
	V_{DD} I/O (3.3 V)	-0.3 to +4.6	
Input voltage (Input Buffer)	V_I	-0.3 to V_{DD} +0.3	
Output voltage (Output Buffer)	V_O	-0.3 to V_{DD} +0.3	
Input current (Input Buffer)	I_I	-10 to +10	mA
Output current per I/O (Output Buffer)	I_O	-24 to +24	
Storage temperature	T_{STG}	-65 to +150	°C

1. Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to the conditions in the other specifications of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Recommended Operating Conditions ($V_{SS} = 0$ V)

Parameter	Symbol	Rated Value	Unit
Power supply voltage	V_{DD} Core (2.5 V)	+2.25 to +2.75	V
	V_{DD} I/O (3.3 V)	+3.0 to +3.6	
Junction temperature	T_j	-40 to +85	°C

DC Characteristics (V_{DD} Core = 2.25 to 2.75 V, V_{DD} I/O = 3.0 to 3.6 V, V_{SS} = 0 V, T_j = -40° to +85°C)

Parameter	Symbol	Conditions	Rated Value			Unit
			Min.	Typ. [1]	Max.	
High-level input voltage	V _{IH}	TTL input (normal), V _{DD} = V _{DD} I/O	2.0	—	V _{DD} +0.3	V
Low-level input voltage	V _{IL}	TTL input (normal)	-0.3	—	0.8	
TTL-level Schmitt	V _{t+}	TTL input	—	1.5	2.0	
Trigger input buffer	V _{t-}		0.7	1.0	—	
Threshold voltage	ΔV _t	V _{t+} - V _{t-}	0.4	0.5	—	
High-level output voltage (Output buffer)	V _{OH}	I _{OH} = -100 μA, V _{DD} = V _{DD} I/O	V _{DD} -0.2	—	—	μA
		I _{OH} = -1, -2, -4, -6, -8, -12, -24 mA	2.4	—	—	
Low-level output voltage (Output buffer)	V _{OL}	I _{OL} = 100 μA	—	—	0.2	
		I _{OL} = 1, 2, 4, 6, 8, 12, 24 mA	—	—	0.4	
High-level input current (Input buffer)	I _{IH}	V _{IH} = V _{DD}	—	—	10	
		V _{IH} = V _{DD} (50-kΩ pull-down)	10	66	200	
Low-level input current (Normal input buffer)	I _{IL}	V _{IL} = V _{SS}	-10	—	10	mA
		V _{IL} = V _{SS} (50-kΩ pull-up)	-200	-66	-10	
		V _{IL} = V _{SS} (3-kΩ pull-up)	-3.3	-1.1	-0.3	
3-state output leakage current (Normal input buffer)	I _{OZH}	V _{OH} = V _{DD}	-10	—	10	μA
		V _{OH} = V _{DD} (50-kΩ pull-down)	10	66	200	
	I _{OZL}	V _{OL} = V _{SS}	-10	—	10	
		V _{OL} = V _{SS} (50-kΩ pull-up)	-200	-66	-10	
		V _{OL} = V _{SS} (3-kΩ pull-up)	-3.3	-1.1	-0.3	
Stand-by current [2]	I _{DDQ}	Output open, V _{IH} = V _{DD} , V _{IL} = V _{SS}	Design Dependent			μA

1. Typical condition is V_{DD} I/O = 3.3 V, V_{DD} Core = 2.5 V, and T_j = 25°C on a typical process.

2. RAM/ROM should be in powerdown mode.

DC Characteristics (V_{DD} Core = 2.25 to 2.75 V, V_{DD} I/O = 3.0 to 3.6 V, V_{SS} = 0 V, T_j = -40° to +125°C)

Parameter	Symbol	Conditions	Rated Value			Unit
			Min.	Typ. ^[1]	Max.	
High-level input voltage	V_{IH}	TTL input (normal), $V_{DD}=V_{DD}$ I/O	2.0	—	$V_{DD} + 0.3$	V
Low-level input voltage	V_{IL}	TTL input (normal)	-0.3	—	0.8	
TTL-level Schmitt	V_{t+}	TTL input	—	1.5	2.0	
Trigger input buffer	V_{t-}		0.7	1.0	—	
Threshold voltage	ΔV_t	$V_{t+} - V_{t-}$	0.4	0.5	—	
High-level output voltage (Output buffer)	V_{OH}	$I_{OH} = -100 \mu A$, $V_{DD}=V_{DD}$ I/O	$V_{DD} - 0.2$	—	—	
		$I_{OH} = -1, -2, -4, -6, -8, -12, -24 mA$	2.35	—	—	
Low-level output voltage (Output buffer)	V_{OL}	$I_{OL} = 100 \mu A$	—	—	0.2	
		$I_{OL} = 1, 2, 4, 6, 8, 12, 24 mA$	—	—	0.45	
High-level input current (Input buffer)	I_{IH}	$V_{IH} = V_{DD}$	—	—	50	μA
		$V_{IH} = V_{DD}$ (50-k Ω pull-down)	10	66	200	
Low-level input current (Normal input buffer)	I_{IL}	$V_{IL} = V_{SS}$	-50	—	50	
		$V_{IL} = V_{SS}$ (50-k Ω pull-up)	-200	-66	-10	
		$V_{IL} = V_{SS}$ (3-k Ω pull-up)	-3.3	-1.1	-0.3	
3-state output leakage current (Normal input buffer)	I_{OZH}	$V_{OH} = V_{DD}$	-50	—	50	μA
		$V_{OH} = V_{DD}$ (50-k Ω pull-down)	10	66	200	
	I_{OZL}	$V_{OL} = V_{SS}$	-50	—	50	
		$V_{OL} = V_{SS}$ (50-k Ω pull-up)	-200	-66	-10	
		$V_{OL} = V_{SS}$ (3-k Ω pull-up)	-3.3	-1.1	-0.3	
Stand-by current ^[2]	I_{DDQ}	Output open, $V_{IH} = V_{DD}$, $V_{IL} = V_{SS}$	Design Dependent			μA

1. Typical condition is V_{DD} I/O = 2.5 V, V_{DD} Core = 2.5 V, and T_j = 25°C for a typical process.

2. RAM/ROM should be in powerdown mode.

DC Characteristics (V_{DD} Core = 2.25 to 2.75 V, V_{DD} I/O = 2.25 to 2.75 V, V_{SS} = 0 V, T_j = -40° to +125°C)

Parameter	Symbol	Conditions	Rated Value			Unit
			Min.	Typ. [1]	Max.	
High-level input voltage	V _{IH}	TTL input (normal), V _{DD} =V _{DD} I/O	1.7	-	V _{DD} + 0.3	V
Low-level input voltage	V _{IL}	TTL input (normal)	-0.3	-	0.7	
TTL- level Schmitt	V _{t+}	TTL input (normal)	-	-	1.7	
Trigger input buffer	V _{t-}		0.6	-	-	
Threshold voltage	ΔV _t	V _{t+} - V _{t-}	-	0.4	-	
High-level output voltage (Output buffer)	V _{OH}	I _{OH} = -100 μA, V _{DD} =V _{DD} I/O	V _{DD} - 0.2	-	-	
		I _{OH} = -0.5, -1, -2, -3, -4, -6, -12 mA	1.95	-	-	
Low-level output voltage (Output buffer)	V _{OL}	I _{OL} = 100 μA	-	-	0.2	
		I _{OL} = -0.5, 1, 2, 3, 4, 6, 12 mA	-	-	0.45	
High-level input current (Input buffer)	I _{IH}	V _{IH} = V _{DD}	-50	-	50	μA
Low-level input current (Normal input buffer)	I _{IL}	V _{IL} = V _{SS}	-50	-	50	
		V _{IL} = V _{SS} (3-kΩ pull-up)	-	-0.8	-	mA
3-state output leakage current (Normal input buffer)	I _{OZH}	V _{OH} = V _{DD}	-50	-	50	μA
	I _{OZL}	V _{OL} = V _{SS}	-50	-	50	
		V _{OL} = V _{SS} (3-kΩ pull-up)	-	-0.8	-	mA
Stand-by current [2]	I _{DDQ}	Output open, V _{IH} = V _{DD} , V _{IL} = V _{SS}	Design Dependent			μA

1. Typical condition is V_{DD} I/O = 2.5 V, V_{DD} Core = 2.5 V, and T_j = 25°C for a typical process.
2. RAM/ROM should be in powerdown mode.

AC Characteristics (Core $V_{DD} = 2.5$ V, $V_{SS} = 0$ V, $T_j = 25^\circ\text{C}$)

Parameter		Driving Type	Conditions [1] [2]	Rated Value [3]	Unit
Internal gate propagation delay	Inverter	1X	F/O = 2, L = 0 mm $V_{DD} = 2.5$ V	0.080	ns
		2X		0.072	
		4X		0.061	
	2-input NAND	1X		0.118	
		2X		0.102	
		4X		0.094	
	2-input NOR	1X		0.134	
		4X		0.127	
	Inverter	1X		0.204	
		2X		0.159	
		4X		0.108	
	2-input NAND	1X		0.274	
		2X		0.183	
		4X		0.136	
	2-input NOR	1X		0.329	
		4X		0.219	
Toggle frequency			F/O = 1, L = 0 mm	1100	MHz

1. Input transition time in 0.15 ns / 2.5 V.
2. Typical condition is $V_{DD} = 2.5$ V and $T_j = 25^\circ\text{C}$ for a typical process.
3. Rated value is calculated as an average of the L-H and H-L delay times of each macro type on a typical process.

AC Characteristics (I/O $V_{DD} = 3.3$ V, $V_{SS} = 0$ V, $T_j = 25^\circ\text{C}$)

Parameter		Conditions		Rated Value	Unit
Input buffer propagation delay		F/O = 2, L = standard wire length		0.311	ns
Output buffer propagation delay	Push-pull Normal output buffer	4 mA	CL = 20 pF	1.783	ns
		8 mA	CL = 50 pF	2.011	ns
		12 mA	CL = 100 pF	2.562	ns
Output buffer transition time [1]	Push-pull Normal output buffer	12 mA	CL = 100 pF	3.325 (r)	ns
		12 mA	CL = 100 pF	3.043 (f)	ns

1. Output rising and falling times are both specified over a 10 to 90% range.

MACRO LIBRARY

Oki Semiconductor supports a wide range of macrocells and macrofunctions, ranging from simple hard macrocells for basic Boolean operations to large, user-parameterizable macrofunctions. The following figure illustrates the main classes of macrocells and macrofunctions available.

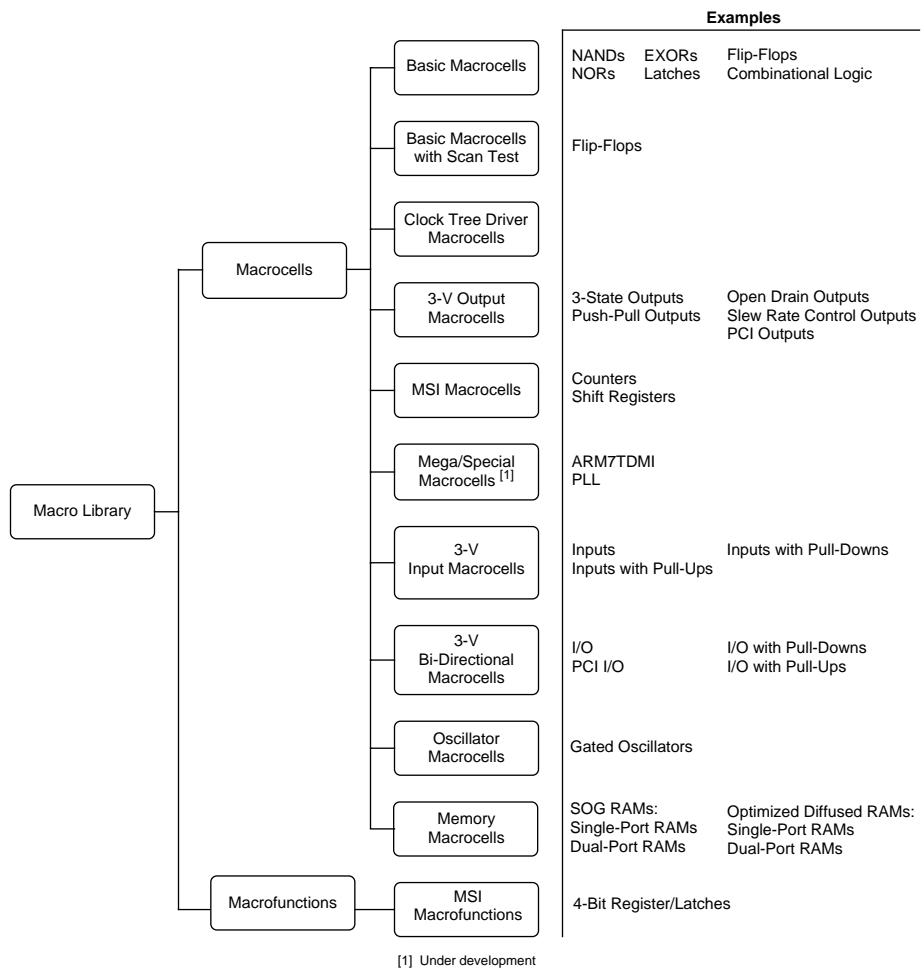


Figure 10. Oki Macrocell and Macrofunction Library

Macrocells for Driving Clock Trees

Oki offers clock-tree drivers that minimize clock skew. The advanced layout software uses dynamic driver placement and sub-trunk allocation to optimize the clock-tree implementation for a particular circuit. Features of the clock-tree driver-macrocells include:

- True RC back annotation of the clock network
- Automatic fan-out balancing
- Dynamic sub-trunk allocation
- Single clock tree driver logic symbol
- Automatic branch length minimization
- Dynamic driver placement
- Up to four clock trunks

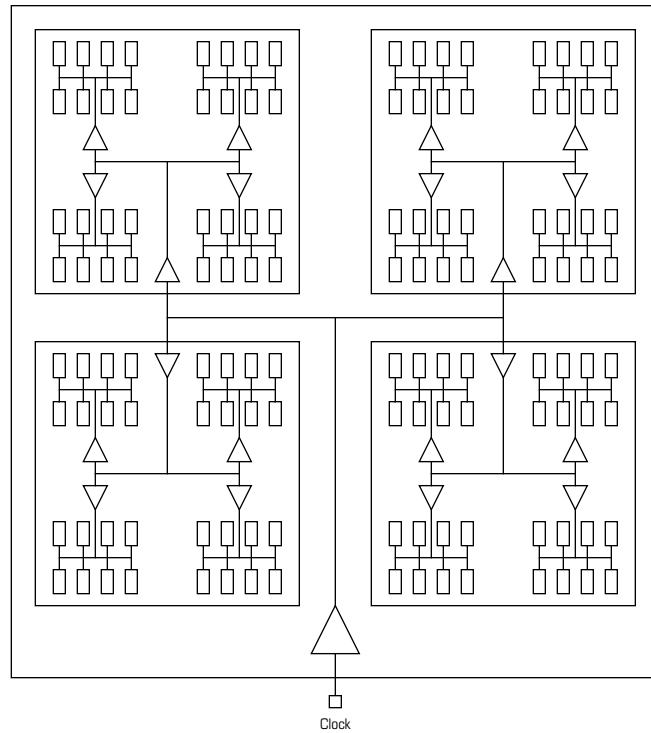


Figure 11. Clock Tree Structure

OKI ADVANCED DESIGN CENTER CAD TOOLS

Oki's advanced design center CAD tools include support for the following:

- Floorplanning for front-end simulation and back-end layout control
- Clock tree structures improve first-time silicon success by eliminating clock skew problems
- JTAG Boundary scan support
- Power calculation which predicts circuit power under simulation conditions to accurately model package requirements

Vendor	Platform	Operating System ^[1]	Vendor Software/Revision ^[1]	Description
Cadence	HP9000, 7xx IBM RS6000 Sun ^[2]	HP-UX AIX SunOS, Solaris	Composer TM Verilog TM NC-Verilog TM Veritime TM Verifault TM Concept TM [3] Leapfrog TM	Design capture Simulation Simulation Timing analysis Fault grading Design capture VHDL simulation
IKOS	HP9000, 7xx, Sun ^[2]	HP-UX, SunOS, Solaris	NSIM Gemini/Voyager	Simulation
Mentor Graphics TM	HP9000, 7xx Sun ^[2]	HP-UX SunOS, Solaris	IDEA TM QuickVHDL QuickSim II TM DFT Advisor Fastscan	Design capture VHDL simulation Logic simulation Test synthesis ATPG
Model Technology Inc. (MTI)	HP9000, 7xx Sun ^[2] PC	HP-UX SunOS, Solaris Win/NT TM	V-System	VHDL simulation
Synopsys (Interface to Mentor Graphics, VIEWLogic)	IBM RS6000 HP9000, 7xx Sun ^[2]	AIX HP-UX SunOS, Solaris	Design Compiler TM HDL/VHDL Compiler TM Test Compiler TM VSS TM	Compilation Design synthesis Test synthesis VHDL simulation
VIEWLogic	PC Sun ^[2]	Windows TM , Win/NT TM [4] SunOS, Solaris	Powerview TM Fusion HDL	Simulation VHDL/Verilog TM Simulation

1. Contact Oki Application Engineering for current software versions.
2. Sun or Sun-compatible.
3. Sun and HP platform only.
4. In development.

Design Process

The following figure illustrates the overall IC design process, also indicating the three main interface points between external design houses and Oki ASIC Application Engineering.

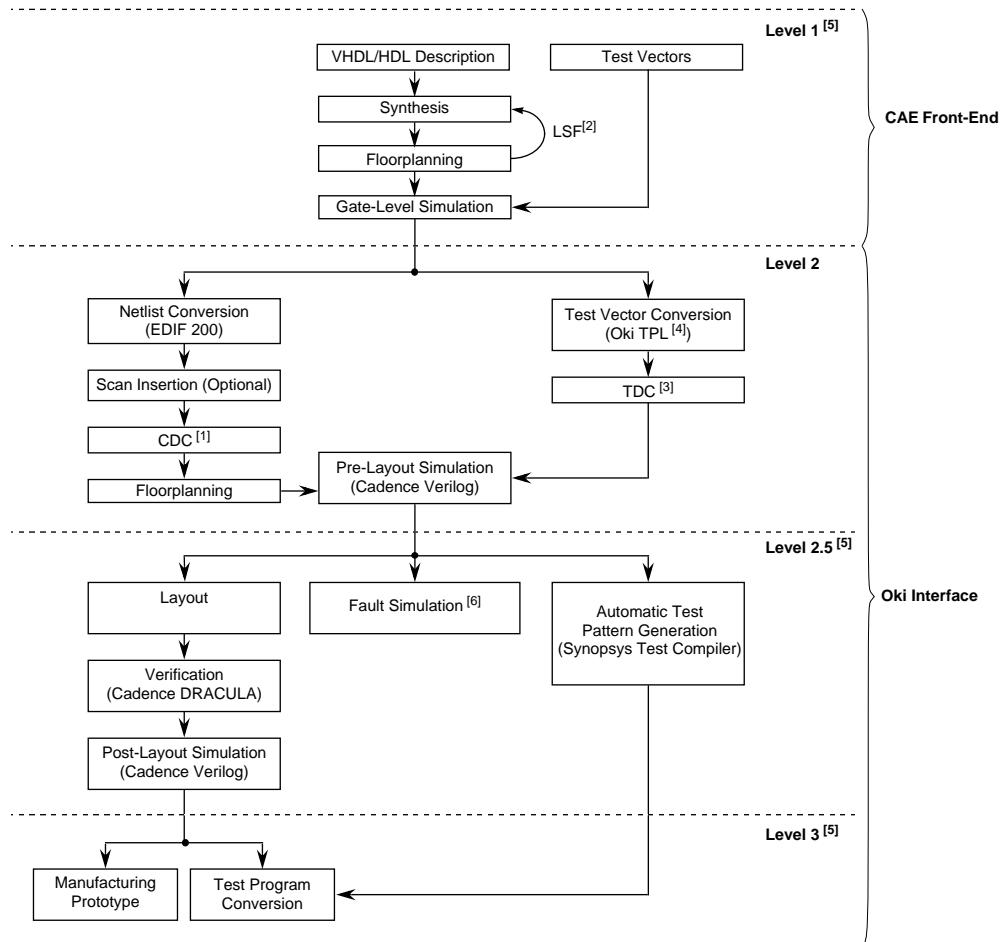


Figure 12. Oki's Design Process

Automatic Test Pattern Generation

Oki's 0.25μm ASIC technologies support ATPG using full scan-path design techniques, including the following:

- Increases fault coverage $\geq 95\%$
- Uses Synopsys Test Compiler
- Automatically inserts scan structures
- Connects scan chains
- Traces and reports scan chains
- Checks for rule violations
- Generates complete fault reports
- Allows multiple scan chains
- Supports vector compaction

ATPG methodology is described in detail in Oki's 0.25μm Scan Path Application Note.

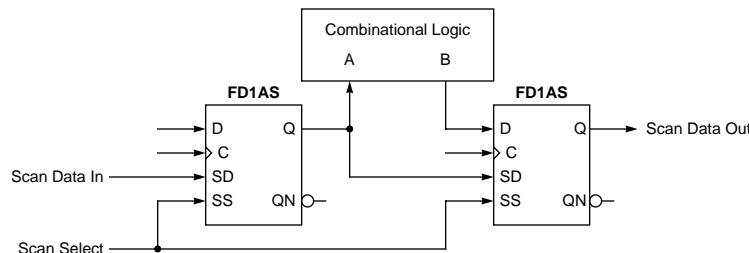


Figure 13. Full Scan Path Configuration

Floorplanning Design Flow

Oki offers two floorplanning tools for high-density ASIC design: Cadence DP3, and Gambit GFP. The two main purposes for Oki's floorplanning tools are to:

- Ensure conformance of critical circuit performance specifications
- Shorten overall design TAT

In a traditional design approach with synthesis tools, timing violations after prelayout simulation are fixed by manual editing of the netlist. This process is difficult and time consuming. Also, there is no physical cluster information provided in the synthesis tool, and so it is difficult to synthesize logic using predicted interconnection delay due to wire length. Synthesis tools may therefore create over-optimized results.

To minimize these problems, Synopsys proposed a methodology called, "Links to Layout (LTL)". Based on this methodology, Oki developed an interface between Oki's Floorplanner and the Synopsys environment, called Link Synopsys to Floorplanner (LSF). As not every Synopsys user has access to the Synopsys Floorplan Management tool, Oki had developed the LSF system to support both users who can access Synopsys Floorplan Management and users who do not have access to Synopsys Floorplan Management.

More information on OKI's floorplanning capabilities is available in Oki's Application Note, *Using Oki's Floorplanner: Standalone Operation and Links to Synopsys*.

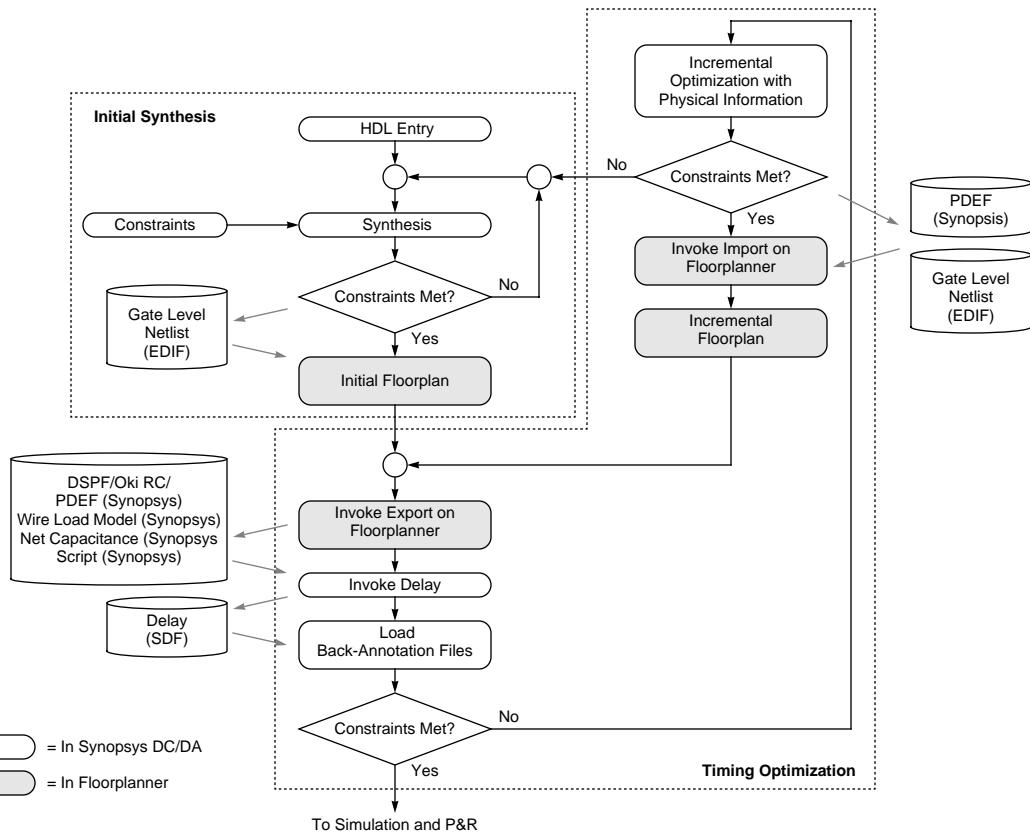


Figure 14. LSF System Design Flow

IEEE JTAG Boundary Scan Support

Boundary scan offers efficient board-level and chip-level testing capabilities. Benefits resulting from incorporating boundary-scan logic into a design include:

- Improved chip-level and board-level testing and failure diagnostic capabilities
- Support for testing of components with limited probe access
- Easy-to-maintain testability and system self-test capability with on-board software
- Capability to fully isolate and test components on the scan path
- Built-in test logic that can be activated and monitored
- An optional Boundary Scan Identification (ID) Register

■ MG113P/114P/115P/73P/74P/75P ■

Oki's boundary scan methodology meets the JTAG Boundary Scan standard, IEEE 1149.1-1990. Oki supports boundary scan on both Sea of Gates (SOG) and Customer Structured Array (CSA) ASIC technologies. Either the customer or Oki can perform boundary-scan insertion. More information is available in Oki's *JTAG Boundary Scan Application Note*. (Contact the Oki Application Engineering Department for interface options.)

PACKAGE OPTIONS

TQFP, LQFP and QFP Package Menu

Base Array	Product Name	I/O Pads ^[1]	LQFP			QFP		TQFP
			144	176	208	208	240	100
MG11xP14	MG7xPB02	68						●
	MG7xPB04	108						●
	MG7xPB06	148						●
	MG7xPB08	188						●
	MG7xPB10	228			●	●		●
	MG7xPB12	268	●		●	●		●
	MG7xPB14	308	●	●	●	●		●
	MG7xPB16	348	●	●	●	●		●
	MG7xPB18	388	●	●	●	●		●
	MG7xPB20	428	●	●	●	●		●
MG11xP22	MG7xPB22	468	●	●	●	●		●
	MG7xPB24	508	●	●	●	●		●
	MG7xPB26	548	●	●	●	●		●
	MG7xPB28	588	●	●	●	●	●	
	MG7xPB30	628	●	●	●	●	●	
	MG7xPB32	668	●	●	●	●	●	
	MG7xPB34	708	●	●	●	●	●	
	MG7xPB36	748	●	●	●	●	●	
MG11xP28	MG7xPB38	788	●	●	●	●		
	MG7xPB40	828	●	●	●	●		
	MG7xPB42	868	●	●	●	●		
Body Size (mm)			20 x 20	24 x 24	28 x 28	28 x 28	32 x 32	14 x 14
Lead Pitch (mm)			0.5	0.5	0.5	0.5	0.5	0.5

1. I/O Pads can be used for input, output, bi-directional, power, or ground.

● = Available now

■ MG113P/114P/115P/73P/74P/75P ■

BGA Package Menu

Base Array	Product Name	I/O Pads [1]	BGA			
			256	352	420	560
MG11xP14	MG7xPB02	68				
	MG7xPB04	108				
	MG7xPB06	148				
	MG7xPB08	188				
	MG7xPB10	228				
	MG7xPB12	268				
	MG7xPB14	308	●			
	MG7xPB16	348	●			
	MG7xPB18	388	●		●	
	MG7xPB20	428	●		●	
	MG7xPB22	468	●	●	●	
	MG7xPB24	508	●	●	●	
	MG7xPB26	548	●	●	●	
	MG7xPB28	588	●	●	●	
	MG7xPB30	628	●	●	●	
MG11xP18	MG7xPB32	668		●	●	
	MG7xPB34	708		●	●	●
	MG7xPB36	748		●		●
	MG7xPB38	788		●		●
	MG7xPB40	828		●		●
	MG7xPB42	868				●
Body Size (mm)			27x27	35x35	35x35	35x35
Lead Pitch (mm)			1.27	1.27	1.27	1.00
Ball Count			256	352	420	560
Signal I/O			231	304	352	400
Power Ball			12	16	32	80
GND Ball			13	32	36	80

1. I/O Pads can be used for input, output, bi-directional, power, or ground.

● = Available now

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